



# Timepix4 Characterization with Monochromatic X-Ray Synchrotron Beam

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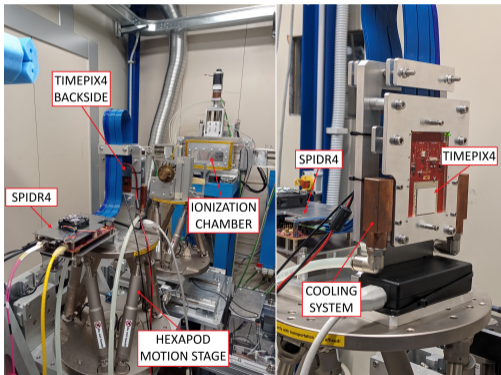
## Timepix4

- ▶ Last Application-Specific Integrated Circuit (ASIC) of the Timepix family (Medipix4 collaboration)
- ▶ Different materials and thicknesses sensors connected to the ASIC via bump-bonding
- ▶ Hybrid pixelated detection system: 448x512 pixels with a 55  $\mu\text{m}$  pitch (24.64 mm x 28.16 mm)

### Operating Modes

- ▶ Frame-based photon counting
- ▶ Data-driven photon counting
- ▶ ToA-ToT data-driven mode:
  - ▶ Time-of-Arrival (**ToA**) measured with a bin width of 195 ps
  - ▶ Time-over-Threshold (**ToT**) measured with a bin width of 1.56 ns
  - ▶ Max rate:  $3.6 \cdot 10^6$  hits/ $\text{mm}^2 \cdot \text{s}$  (16 x10 Gbps fast link)

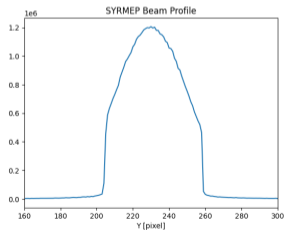
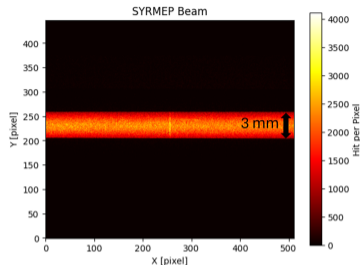
# Data Acquisition System



- ▶ **Timepix4-v2** assembly:
  - ▶ 300  $\mu\text{m}$  p-on-n Si sensor
  - ▶ ToA-ToT data-driven mode
  - ▶ Thr: 1000  $e^-$  (3.6 keV)
  - ▶ Bias: 100 V
- ▶ **SPIDR4** control board (2x2.56 Gbps fast link)
- ▶ **Custom software**: acquisitions with online monitor and analysis
- ▶ Custom **cooling system** to keep Timepix4 at 15 °C
  - ▶ Chiller
  - ▶ Copper heat exchanger
- ▶ **2 Hexapod Motion Station**:
  - ▶ Timepix4 and SIPDR4
  - ▶ Lead edge (spatial response measurements)
- ▶ **Ionization chamber** to monitor the beam intensity

## The Monochromatic Beam

- ▶ **Monochromatic X-rays laminar beam** of SYRMEP beamline at ELETTRA Synchrotron in Trieste
- ▶ **Beam energy** selected by acting on the orientation of the two crystals monochromator (8.5 - 40 keV)
- ▶ **Beam intensity** set by varying the relative angle of the crystals (rocking fraction) and applying Al filters
- ▶ **Beam geometry**: 3.0 mm × 28.6 mm cross section on the detector (tungsten slits), Gaussian profile



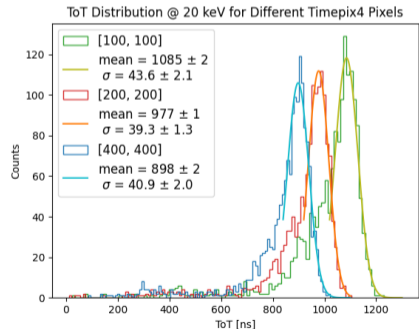
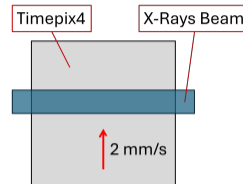
# Timepix4 Energy Calibration

## Data Acquisitions

- ▶ **Full-matrix monochromatic acquisitions** obtained by moving the Timepix4 at a constant speed of 2 mm/s along the fixed X-rays beam:
  - ▶ 18 energies in the range 8.5 keV - 40 keV
  - ▶  $\sim 4000$  hits/pixel

## Data Analysis

- ▶ Hits clusterization: only cluster size = 1 events used in the calibration
- ▶ Pixel by pixel analysis: gaussian fit on the ToT spectra



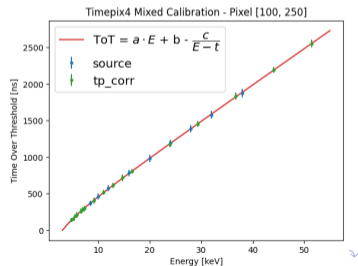
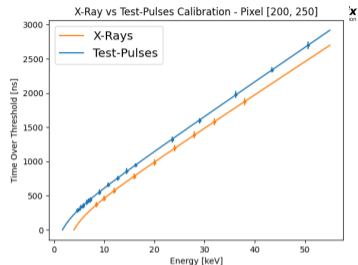
# Timepix4 Energy Calibration

## Test-Pulses Acquisitions and Analysis

- ▶ Timepix4 calibration curve non-linear in the low energy region
- ▶ **Internally generated test-pulses acquisition**
  - ▶ 17 energies in the nominal range 4.7 keV- 50.7 keV (500 hits/pixel)
- ▶ Test-pulses and X-rays: different calibration curves in ToT vs Energy plots
- ▶ Test-pulses acquisitions corrected introducing two parameters:
  - ▶ **Slope Correction:**  $E_{TP} \rightarrow E_{TP} \cdot g_{i,j}$
  - ▶ **ToT Offset Correction:**  $ToT_{TP} \rightarrow ToT_{TP} + h_{i,j}$

## Timepix4 Calibration Curve

- ▶ Pixel per pixel fit of the Timepix4 calibration function on the ToT vs Energy plot:
 
$$ToT = a \cdot E + b - \frac{c}{E - t}$$
- ▶ ToT to Energy conversion parameters:  $a_{i,j}$ ,  $b_{i,j}$ ,  $c_{i,j}$  and  $t_{i,j}$



## Timepix4 Energy Calibration

### Calibration Results

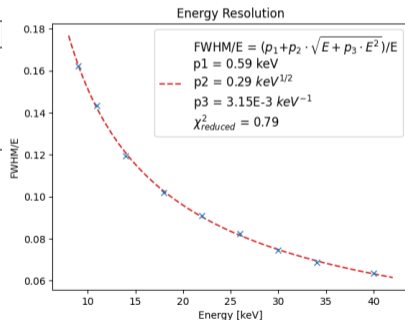
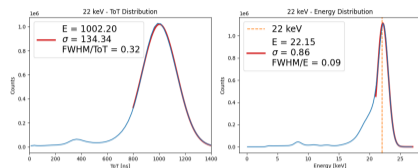
- ▶ Full matrix **ToT spectra** → **Energy spectra** (all cluster size)
  - ▶ Energy peaks are systematically narrower than ToT peaks
- ▶ Photopeaks characterization via Gaussian fit:

X-Rays Energy [keV]	$E_{measured}$ [keV]	$FWHM/E_{measured}$
9	9.0	0.16
22	22.1	0.09
30	30.1	0.07
40	40.0	0.06

### Energy Resolution Function

- ▶ **Energy resolution** evaluated by fitting the  $FWHM/E$  vs Energy points with the Gaussian energy broadening function:

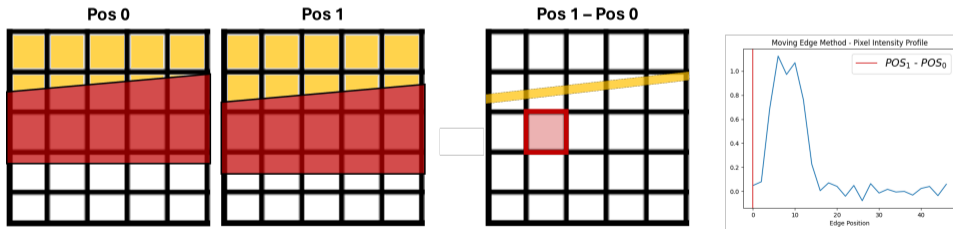
$$\frac{\Delta E}{E} = \frac{p_1 + p_2 \cdot \sqrt{E + p_3 \cdot E^2}}{E}$$





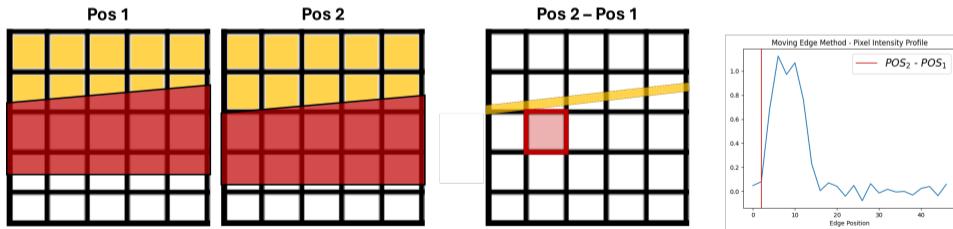
## Timepix4 Spatial Response: Moving Edge Method

- ▶ **Multiple acquisitions of an edge** shifted by a fixed step (shorter than pixel pitch)
- ▶ **ESF** → **LSF**: difference between each image and the one acquired in the previous position
- ▶ In each pixel, the intensity as a function of the slit position is measured
- ▶ Different pixel results combined to improve the statistics



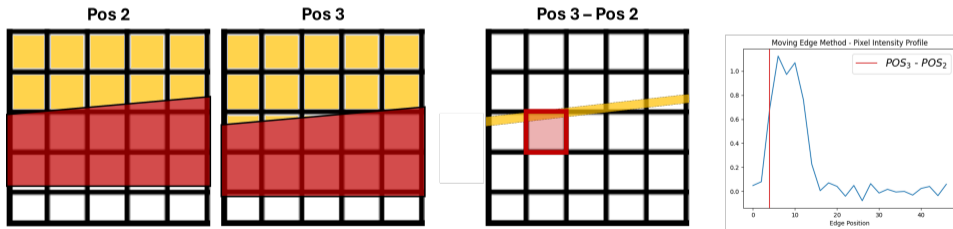
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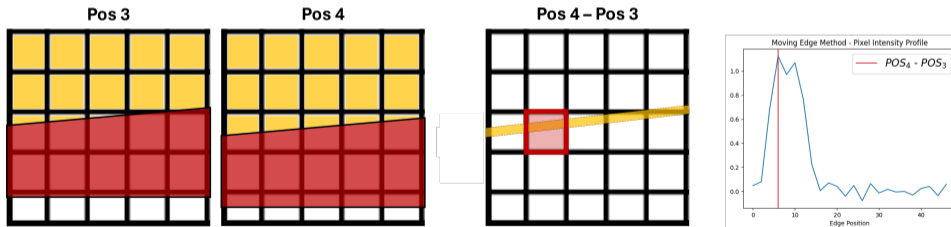
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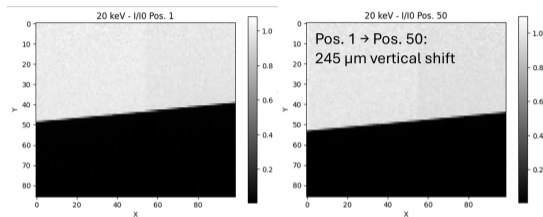
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## Timepix4 Spatial Response

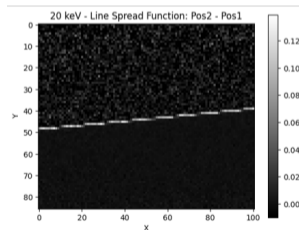
### Data Acquisitions

- ▶ **Lead edge** in front of the detector ( $5.5^\circ$  tilt)
- ▶ 5  $\mu\text{m}$  steps vertical shift
- ▶ 50 position: 245  $\mu\text{m}$  total shift
- ▶ Energies: 10 keV, 20 keV



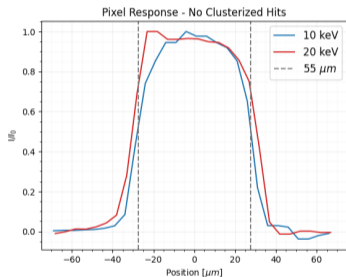
### Data Analysis

- ▶ Four images for each position:
  - ▶ **No clusterized events**
  - ▶ **Clusterized events**
  - ▶ **Cluster size = 1 events**
  - ▶ **Cluster size = 2 events**
- ▶ Flat-field correction for each image
- ▶ Moving Edge Analysis: **ESF**  $\rightarrow$  **LSF**



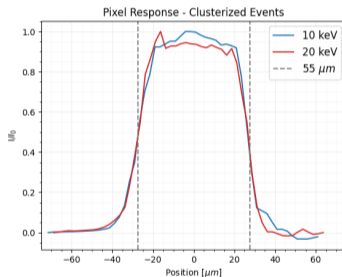
# Timepix4 Spatial Response: Normalized LSF (thr = 3.6 keV)

## No Clusterized Events



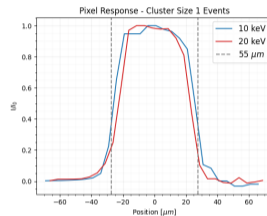
- ▶  $FWHM_{10\text{keV}} = 58 \mu\text{m}$
- ▶  $FWHM_{20\text{keV}} = 61 \mu\text{m}$
- ▶ FWHM larger than pixel pitch (55  $\mu\text{m}$ )  
→ charge sharing

## Clusterized Events

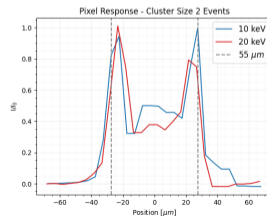


- ▶  $FWHM_{10\text{keV}} = 55 \mu\text{m}$
- ▶  $FWHM_{20\text{keV}} = 55 \mu\text{m}$
- ▶ FWHM match with pixel pitch →  
charge sharing corrected by clusterization

## Cluster Size = 1



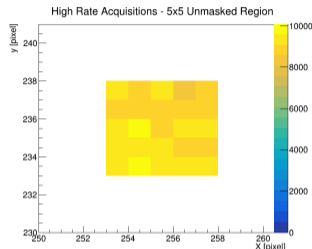
## Cluster Size = 2



# High Rate Measurements

## Data Acquisitions

- ▶ **High rate acquisitions** → few pixels unmasked (5x5 pixel region) to avoid readout bandwidth saturation (2x2.56 Gbps fast link)
- ▶ Photon rate monitored using a ionization chamber
- ▶ Energies:
  - ▶ **11 keV:**  $2.7 \cdot 10^4 - 1.7 \cdot 10^8$  absorbed photon  $mm^{-2}s^{-1}$
  - ▶ **20 keV:**  $1.9 \cdot 10^6 - 3.2 \cdot 10^7$  absorbed photon  $mm^{-2}s^{-1}$



## Paralyzable and Non-Paralyzable Models

Fit of the electronics paralyzable and non-paralyzable model on pixel counts:

- ▶ **Paralyzable Model:**

$$m = n \cdot e^{-n \cdot \tau} = I_{IOC} \cdot A \cdot e^{-I_{IOC} \cdot A \cdot \tau}$$

$m$ : measured hits rate per pixel [ $hits\ s^{-1}$ ]

$n$ : expected hits rate per pixel [ $hits\ s^{-1}$ ]

$I_{IOC}$ : ionization chamber current [nA]

$A$ : conversion factor

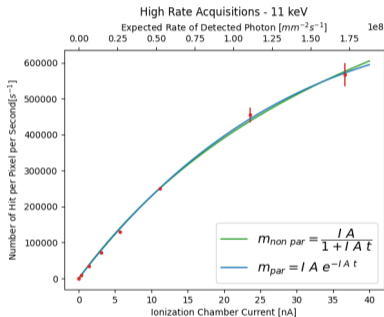
$\tau$ : pixel dead time

- ▶ **Non Paralyzable Model:**

$$m = \frac{n}{1 - n \cdot \tau} = \frac{I_{IOC} \cdot A}{1 - I_{IOC} \cdot A \cdot \tau}$$

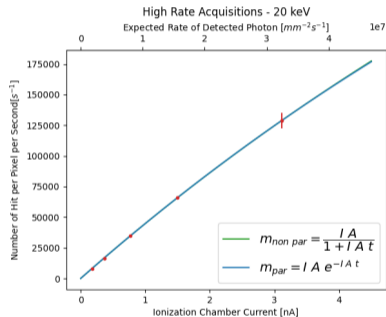
# High Rate Measurements - Results

## 11 keV



- ▶  $\tau_{paralyzable} = 544 \pm 16$  ns
- ▶  $\tau_{non\ paralyzable} = 746 \pm 54$  ns
- ▶  $ToT_{11\ keV} \simeq 388$  ns

## 20 keV



- ▶  $\tau_{paralyzable} = 760 \pm 56$  ns
- ▶  $\tau_{non\ paralyzable} = 817 \pm 67$  ns
- ▶  $ToT_{20\ keV} \simeq 662$  ns



# Timepix4 Characterization with Monochromatic Synchrotron X-Ray Beam - Conclusions

## Energy Characterization

- ▶ Timepix4 energy resolution after calibration (6 % at 40 keV) is compatible with literature results (Timepix assembly with 300  $\mu\text{m}$  Si sensors)

## Spatial Response

- ▶ Event clusterization:  $FWHM_{20 \text{ keV}}$ : 61  $\mu\text{m}$   $\rightarrow$  55  $\mu\text{m}$

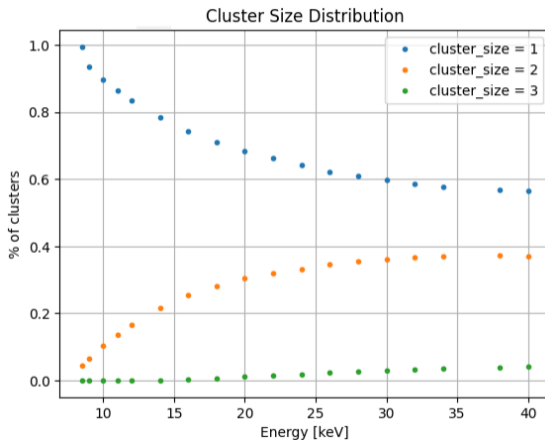
## High Rate Acquisitions

- ▶ Pixel count is linear up to high photon rate ( $\sim 4 \cdot 10^7$  hits  $\cdot \text{mm}^{-2} \text{s}^{-1}$  at 11 keV)
- ▶ More investigation are needed to study the pixel dead time dependence on photon energy and on the Timepix4 configuration parameters (Ikrom)

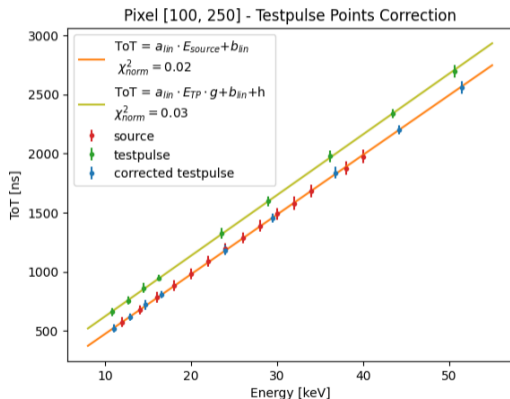
# Thanks for your Attention!



# Cluster Size Distribution



# Testpulse Points Correction



- ▶  $E > 10$  keV - Linear region of the calibration curve
- ▶ For each pixel, a linear fit was performed on source points:

$$ToT = a_{lin} \cdot E_{source} + b_{lin}$$

- ▶ For each pixel, the fit of function:

$$ToT = a_{lin} \cdot E_{testpulse} \cdot g + b_{lin} + h$$

was performed on testpulse points

- ▶ For each pixel, parameters  $g$  and  $h$  to correct the points acquired via testpulse